

PHOTOLUMINESCENCE STUDY OF B-TRION IN CVD GROWN MoS₂ MONOLAYERS

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Two-dimensional semiconductors, namely, transition metal dichalcogenides (TMD) like MoS₂ have interesting physical properties, such as direct bandgap and very high exciton binding energy. The value of spin-orbit valence band splitting in MoS₂ is 146 eV [1]. Due to spin-orbit splitting, the monolayer of MoS₂ has two excitonic bands named A and B bands. The monolayer of MoS₂ has electrically neutral quasiparticles – excitons and if additional charges (electrons or holes) are present either negative or positive charged excitons – trions [2].

Chemical vapour deposition (CVD) method was used to synthesize MoS₂ monolayers on Si/SiO₂ substrate. Different growth regimes were used and the most optimal regime gave MoS₂ monolayers with size

~100 μm . These monolayers were studied using non-resonant and resonant Raman scattering and laser dependent photoluminescence (PL). PL spectra show A and B bands and a defect peak X_D at lower energies (Fig. 1). Defect peak X_D is more pronounced at lower laser intensities. The A band has a peak maximum at around 1.78 eV, which is at lower energy compared to mechanically exfoliated MoS₂ monolayers. This shift is caused by a tensile strain in CVD grown MoS₂ monolayers. By increasing the laser intensity, the B band maximum shifted toward lower energy. This behaviour of the B band has not been detected before and this indicates that the B band consists of the B exciton peak and the B⁺ trion peak with an energy difference about 25 meV.

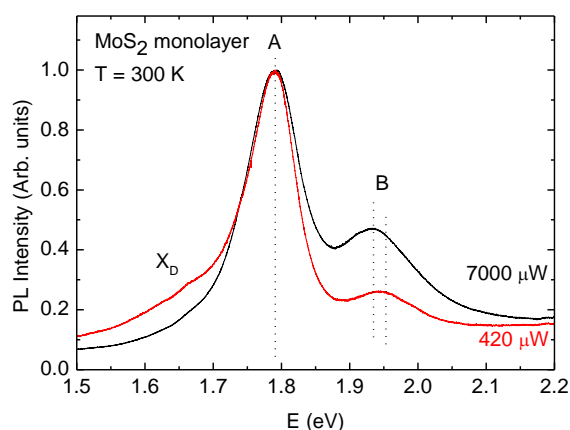


Fig. 1 PL spectra of MoS₂ monolayer at laser intensities 420 μW and 7000 μW .

References

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